

January 1995 Revised November 1999

74ABT241

Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The ABT241 is an octal buffer and line driver with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/

Features

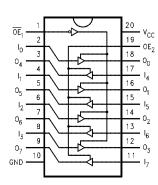
- Non-inverting buffers
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description					
74ABT241CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body					
74ABT241CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide					
74ABT241CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide					
74ABT241CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide					

Device also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
OE ₁	Output Enable Input (Active LOW)
OE ₂	Output Enable Input (Active HIGH)
I ₀ –I ₇	Inputs
O ₀ -O ₇	Outputs

Truth Table

OE ₁	I ₀₋₃	O ₀₋₃	OE ₂	I ₄₋₇	O ₄₋₇
Н	Х	Z	L	X	Z
L	Н	Н	Н	Н	Н
L	L	L	Н	L	L

- H = HIGH Voltage Level L = LOW Voltage Level

- X = Immaterial Z = High Impedance

Absolute Maximum Ratings(Note 1)

-65°C to +150°C

Ambient Temperature under Bias -55° C to $+125^{\circ}$ C Junction Temperature under Bias -55° C to $+150^{\circ}$ C

V_{CC} Pin Potential to Ground Pin -0.5V to +7.0V

 $\begin{array}{ll} \mbox{Input Voltage (Note 2)} & -0.5 \mbox{V to } +7.0 \mbox{V} \\ \mbox{Input Current (Note 2)} & -30 \mbox{ mA to } +5.0 \mbox{ mA} \\ \end{array}$

Voltage Applied to Any Output

in the Disabled or

Storage Temperature

Power-Off State -0.5V to 5.5V in the HIGH State -0.5V to V_{CC}

Current Applied to Output

in LOW State (Max) twice the rated I_{OL} (mA)

DC Latchup Source Current

(Over Comm Operating Range) -500 mA

Over Voltage Latchup (I/O)

Recommended Operating Conditions

Free Air Ambient Temperature -40°C to +85°C Supply Voltage +4.5V to +5.5V

Minimum Input Edge Rate ($\Delta V/\Delta t$)

Data Input 50 mV/ns
Enable Input 20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation

under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Param	eter	Min	Тур	Max	Units	v _{cc}	Conditions
V _{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V _{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V _{CD}	Input Clamp Diode Voltage				-1.2	V	Min	I _{IN} = -18 mA
V _{OH}	Output HIGH Voltage		2.5			V	Min	$I_{OH} = -3 \text{ mA}$
		2.0			V	Min	I _{OH} = -32 mA	
V _{OL}	Output LOW Voltage				0.55	V	Min	I _{OL} = 64 mA
I _{IH}	Input HIGH Current				1 1	μΑ	Max	V _{IN} = 2.7V (Note 4) V _{IN} = V _{CC}
I _{BVI}	Input HIGH Current B	reakdown Test			7	μА	Max	V _{IN} = 7.0V
I _{IL}	Input LOW Current				−1 −1	μА	Max	V _{IN} = 0.5V (Note 4) V _{IN} = 0.0V
V _{ID}	Input Leakage Test		4.75			V	0.0	I _{ID} = 1.9 μA All Other Pins Grounded
I _{OZH}	Output Leakage Current				10	μΑ	0 – 5.5V	$V_{OUT} = 2.7V; \overline{OE}_n = 2.0V$
I _{OZL}	Output Leakage Current				-10	μΑ	0 – 5.5V	$V_{OUT} = 0.5V; \overline{OE}_n = 2.0V$
Ios	Output Short-Circuit Current		-100		-275	mA	Max	V _{OUT} = 0.0V
I _{CEX}	Output High Leakage Current				50	μΑ	Max	V _{OUT} = V _{CC}
I _{ZZ}	Bus Drainage Test				100	μΑ	0.0	V _{OUT} = 5.5V; All Others GND
I _{CCH}	Power Supply Current	t			50	μΑ	Max	All Outputs HIGH
I _{CCL}	Power Supply Current	t			30	mA	Max	All Outputs LOW
I _{CCZ}	Power Supply Current	t			50	μА	Max	$\overline{OE}_n = V_{CC};$ All Others at V_{CC} or Ground
I _{CCT}	Additional I _{CC} /Input	Outputs Enabled			2.5	mA		$V_{I} = V_{CC} - 2.1V$
		Outputs 3-STATE			2.5	mA	Max	Enable Input V _I = V _{CC} - 2.1V
		Outputs 3-STATE			50	μΑ		Data Input $V_I = V_{CC} - 2.1V$ All Others at V_{CC} or Ground
I _{CCD}	Dynamic I _{CC}	Dynamic I _{CC} No Load				mA/ MHz		Outputs Open
	(Note 4)				0.1		Max	$\overline{OE}_n = GND$, (Note 3)
								One Bit Toggling, 50% Duty Cycle

10V

Note 3: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.

Note 4: Guaranteed, but not tested.

DC Electrical Characteristics

(SOIC package)

Symbol	Parameter	Min	Тур	Мах	Units	V _{cc}	Conditions $C_L = 50 \text{ pF},$ $R_L = 500\Omega$
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}		0.5	8.0	V	5.0	T _A = 25°C (Note 5)
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	-1.3	-0.8		V	5.0	T _A = 25°C (Note 5)
V _{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.7	3.1		V	5.0	T _A = 25°C (Note 7)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.0	1.5		V	5.0	T _A = 25°C (Note 6)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		1.1	0.8	V	5.0	T _A = 25°C (Note 6)

Note 5: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 6: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

Note 7: Max number of outputs defined as (n). n - 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

AC Electrical Characteristics

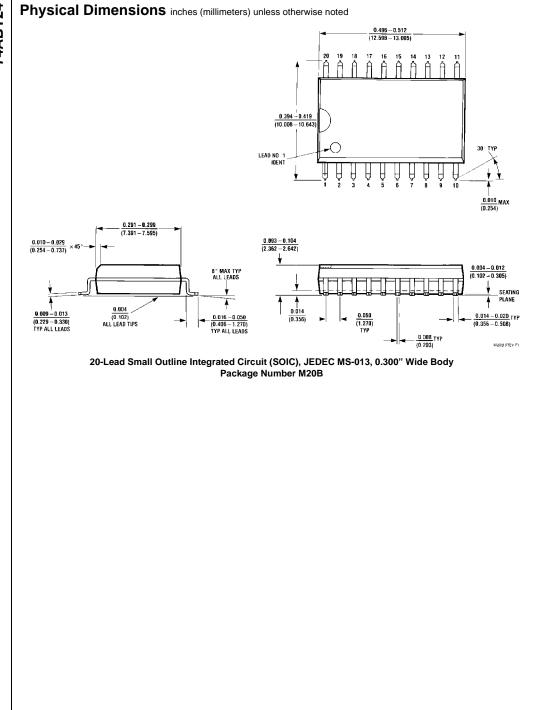
(SOIC and SSOP package)

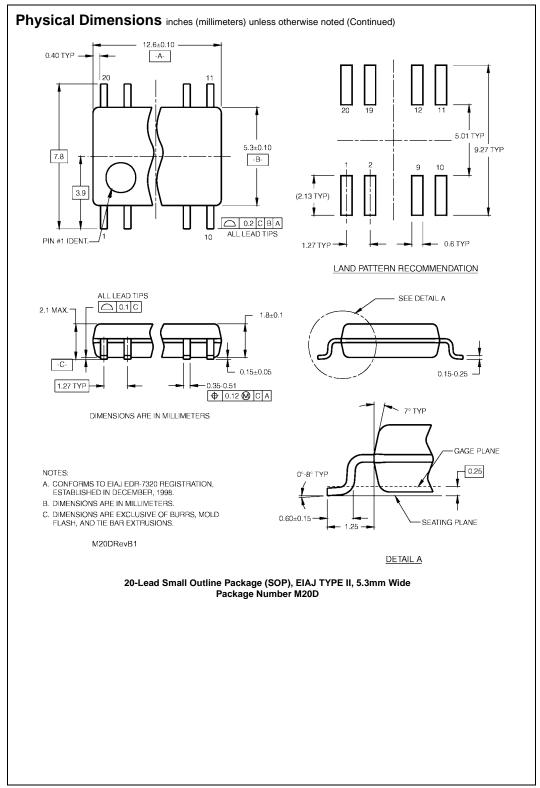
Symbol	Parameter	$T_A = +2!$ $V_{CC} = +$ $C_L = 50$		$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ $V_{CC} = 4.5\text{V} - 5.5\text{V}$ $C_L = 50 \text{ pF}$		Units	
		Min	Тур	Max	Min	Max	
t _{PLH}	Propagation Delay	1.0		4.6	1.0	4.6	20
t _{PHL}	Data to Outputs	1.0		4.6	1.0	4.6	ns
t _{PZH}	Output Enable	1.1		6.8	1.1	6.8	ns
t _{PZL}	Time	1.3		6.8	1.3	6.8	115
t _{PHZ}	Output Disable	1.6		6.8	1.6	6.8	20
t_{PLZ}	Time	1.0		5.9	1.0	5.9	ns

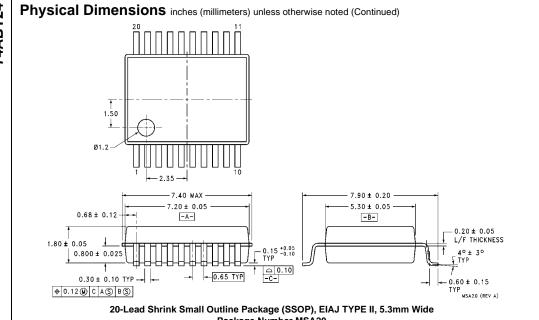
Capacitance

Symbol	Parameter	Тур	Units	Conditions $T_{\Delta} = 25^{\circ}C$
C _{IN}	Input Capacitance	5.0	pF	V _{CC} = 0V
C _{OUT} (Note 8)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

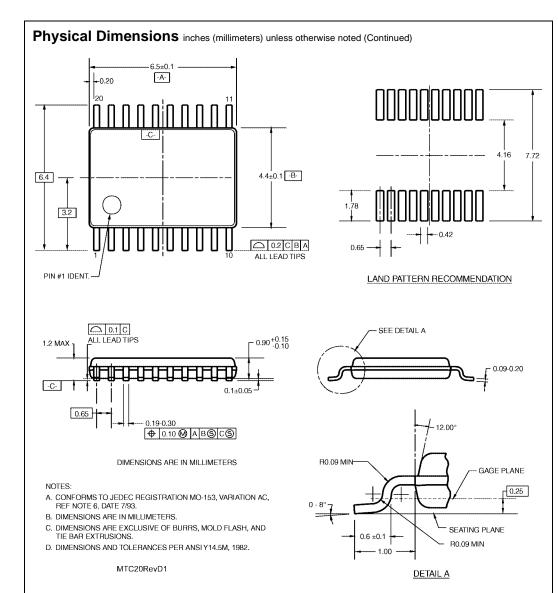
Note 8: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.







20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide Package Number MSA20



20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC20

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